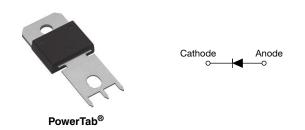


Ultrafast Soft Recovery Diode, 150 A FRED Pt®



PRIMARY CHARACTERISTICS				
I _{F(AV)}	150 A			
V_{R}	200 V			
V _F at I _F	0.77 V			
t _{rr} (typ.)	See recovery table			
T _J max.	175 °C			
Package	PowerTab [®]			
Circuit configuration	Single			

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_{R}		200	V
Continuous forward current	I _{F(AV)}	T _C = 116 °C	150	
Single pulse forward current	I _{FSM}	T _C = 25 °C	1600	Α
Maximum repetitive forward current	I _{FRM}	Square wave, 20 kHz	380	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MAX.		UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	200	-	-	.,
Forward voltage	V _F	I _F = 150 A	-	0.94	1.10	V
Forward voltage V _F	VF	I _F = 150 A, T _J = 175 °C	-	0.77	0.88	
Devenue legisere evenet		V _R = V _R rated	-	-	50	μΑ
Reverse leakage current	I _R	T _J = 150 °C, V _R = V _R rated	-	-	2	mA
Junction capacitance	C _T	V _R = 200 V		180	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 3.5 - n		nH		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Payaraa raaayany tima	+	T _J = 25 °C		-	48	-	no
Reverse recovery time	t _{rr}	T _J = 125 °C		-	88	-	ns
Deal, was a survey of the state	T _J = 25 °C	I _F = 150 A	-	5	-	۸	
Peak recovery current	ent I _{RRM}	T _J = 125 °C	$V_R = 160 \text{ V}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$	=	12	-	Α
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	120	-	nC
	Q _{rr}	T _J = 125 °C		-	520	-	nc nc

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	0.35	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	- K/VV
Weight			-	-	5.02	g
vveignt			-	0.18	-	OZ.
Mounting torque			1.2 (10)	-	2.4 (20)	N ⋅ m (lbf ⋅ in)
Marking device		Case style PowerTab [®]		150EE	BU02H	

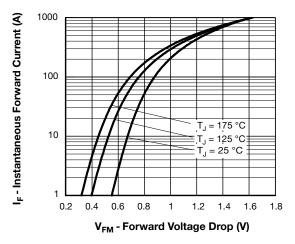


Fig. 1 - Maximum Forward Voltage Drop Characteristics

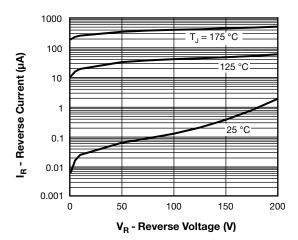


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

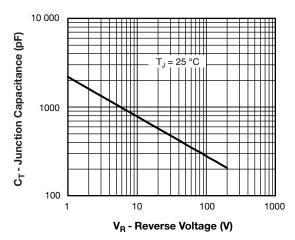


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

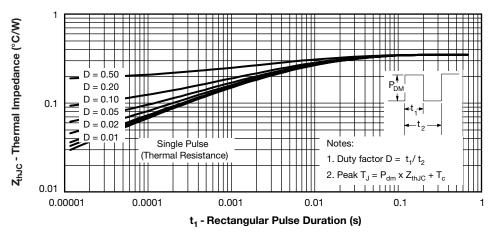


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

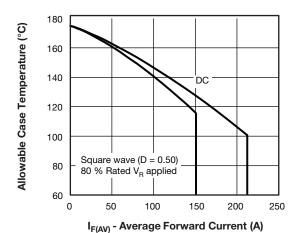


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

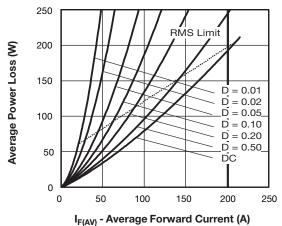


Fig. 6 - Forward Power Loss Characteristics



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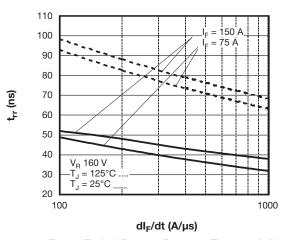


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

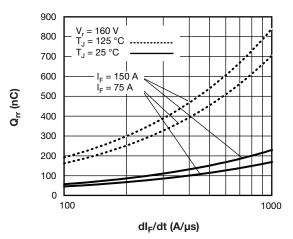
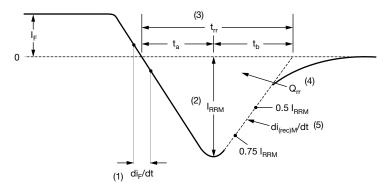


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

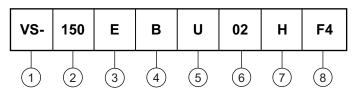
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (150 = 150 A)

3 - Single diode

4 - PowerTab®

5 - Ultrafast recovery

6 - Voltage rating (02 = 200 V)

7 - H = AEC-Q101 qualified

8 - F4 = RoHS-compliant and totally lead (Pb)-free

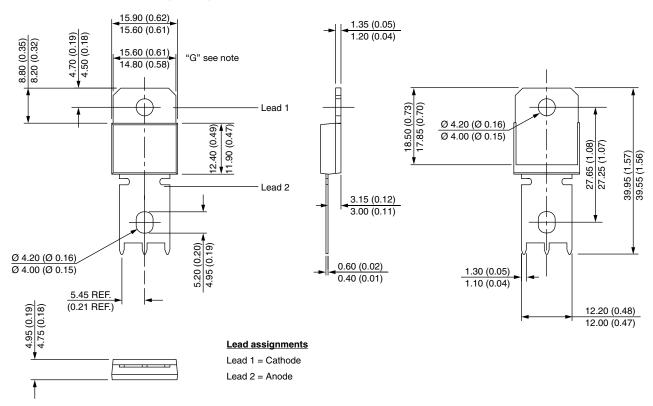
ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-150EBU02HF4	25	375	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			
SPICE model	www.vishay.com/doc?96503			



PowerTab®

DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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